



### SOT-23



### Pin Definition:

1. Output
2. Ground
3. Input

## General Description

The TS61 series are highly precise, low power consumption voltage detectors, manufactured using CMOS and laser trimming technologies. Detect voltage is extremely accurate with minimal temperature drift.

Both CMOS and N-channel open drain output configurations are available.

## Features

- Highly Accurate:  $\pm 2\%$
- Detecting Voltage Temperature Characteristics:  
TYP  $\pm 100\text{ppm}/^\circ\text{C}$
- Low Power Consumption,  $0.7\mu\text{A}$  (typ) @  $V_{\text{IN}}=1.5\text{V}$
- Detect Voltage Range:  $1.6\text{V} \sim 6.0\text{V}$
- Operating Voltage Range:  $0.7\text{V} \sim 10\text{V}$
- Output Configuration:  
N-Channel open drain or CMOS

## Applications

- Battery-operated systems
- Microprocessor reset circuitry
- Memory battery back-up circuits
- Power-on reset circuits
- Power failure detection
- System battery life and charge voltage monitors

## Ordering Information

Part No.	Package	Packing
TS61CxxCX RF	SOT-23	3Kpcs / 7" Reel
TS61NxxCX RF	SOT-23	3Kpcs / 7" Reel

Note:

\* Where **xx** denotes voltage option, available are

**20**= 2.0V

**23**= 2.3V

**24**= 2.4V

**25**= 2.5V

**27**= 2.7V

**30**= 3.0V

**33**= 3.3V

**40**= 4.0V

**42**= 4.2V

**44**= 4.4V

**45**= 4.5V

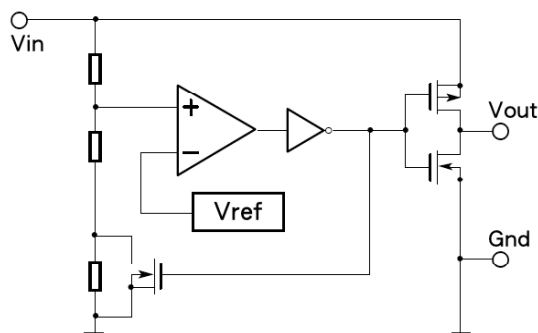
Contact factory for additional voltage option.

\* TS61C: CMOS output

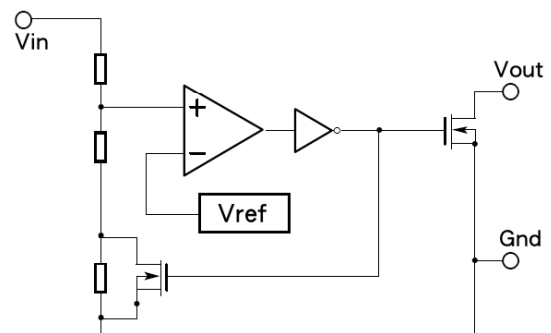
\* TS61N: N-Channel Open Drain Output

## Block Diagram

### CMOS Output



### N-Channel Open Drain Output



### Absolute Maximum Rating

Parameter	Symbol	Maximum	Unit
Input Voltage	$V_{IN}$	+12	V
Output Current	$I_O$	50	mA
Output Voltage	CMOS	(Gnd – 0.3) to ( $V_{IN} + 0.3$ )	V
	N-channel open drain	(Gnd – 0.3) to 12	
Power Dissipation	$P_D$	150	mW
Operating Ambient Temperature Range	$T_A$	-40 ~ +85	°C
Storage Temperature	$T_{STG}$	-65 ~ +150	°C

Note: Stress above those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation section of the specifications is not implied.

### Electrical Specifications ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)

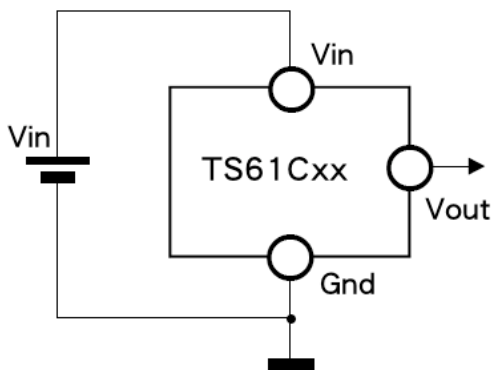
Parameter	Conditions	Symbol	Min	Typ	Max	Unit	Circuit
Detect Voltage		$V_{DF}$	$V_{DFX} 0.98$	$V_{DF}$	$V_{DFX} 1.02$	V	1
Hysteresis range		$V_{HYS} / V_{DF}$	2	--	8	%	1
Supply Current	$V_{IN}=1.5V$	$I_{SS}$	--	0.7	2.3	$\mu\text{A}$	2
	$V_{IN}=2.0V$		--	0.8	2.7		
	$V_{IN}=3.0V$		--	0.9	3.0		
	$V_{IN}=4.0V$		--	1.0	3.2		
	$V_{IN}=5.0V$		--	1.1	3.6		
Operating Voltage	$V_{DF}(T)=1.6V\sim 6V$	$V_{IN}$	0.7	--	10.0	V	1
Output Current	<b>N-channel <math>V_{DS}=5V</math></b>						
	$V_{IN}=1.0V$	$I_{OUT}$	1.0	2.2	--	mA	3
	$V_{IN}=2.0V$		3.0	7.7	--		
	$V_{IN}=3.0V$		5.0	10.1	--		
	$V_{IN}=4.0V$		6.0	11.5	--		
	$V_{IN}=5.0V$		7.0	13.0	--		
<b>P-channel <math>V_{DS}=2.1V</math> (with CMOS output)</b>							
$V_{IN}=8.0V$	$I_{OUT}$	--	-10.0	-2.0	mA	4	
Temperature Characteristics	$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$	$\frac{\Delta V_{DF}}{\Delta T_A \times V_{DF}}$	--	$\pm 100$	--	ppm / °C	--
Delay Time	$V_{DR} \rightarrow V_{OUT}$ inversion	$t_{DLY}$	--	--	0.2	ms	5

Note:  $V_{DF}(T)$ : Established Detect Voltage Value, 1.6V ~ 6.0V  $\pm 2\%$  for Standard Voltage Detectors

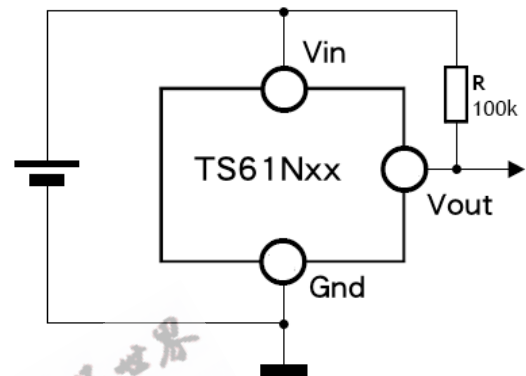
Release Voltage:  $V_{DR} = V_{DF} + V_{HYS}$

### Typical Application Circuit

#### CMOS Output

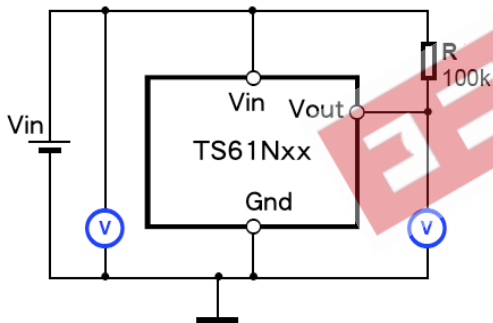


#### N-Channel Open Drain Output



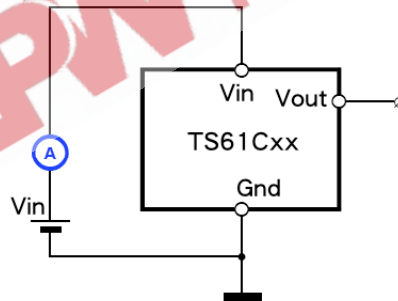
### Measuring Circuit

#### Test Circuit 1

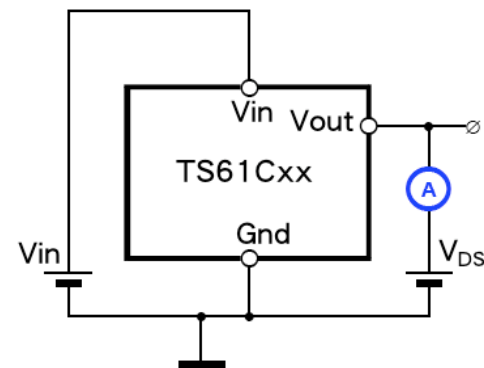


\* Not Necessary with CMOS output product

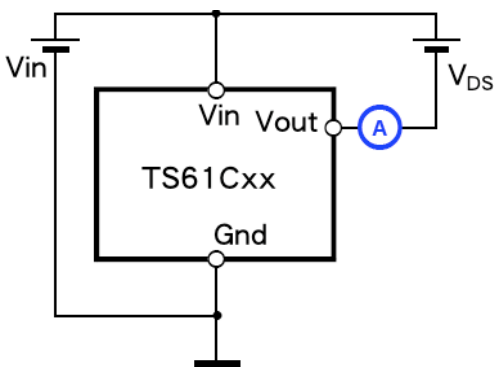
#### Test Circuit 2



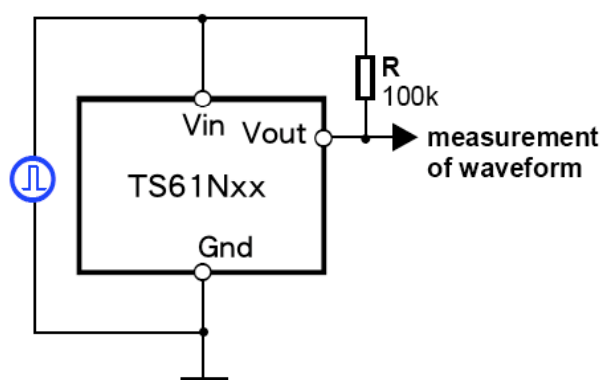
#### Test Circuit 3



#### Test Circuit 4



#### Test Circuit 5



\* Not Necessary with CMOS output products

### Directions for use

1. Please use this IC within the stated maximum ratings. Operation beyond these limits may cause degrading or permanent damage to the device.
2. When a resistor is connected between the  $V_{IN}$  pin and the input CMOS output configurations, oscillation may occur as a result of voltage drops at  $R_{IN}$  if load current ( $I_{OUT}$ ) exists. (refer to the Oscillation Description ① below).
3. When a resistor is connected between the  $V_{IN}$  pin and the input with CMOS output configurations, irrespective of N-ch output configurations, oscillation may occur as a result of through current at the time of voltage release even if load current ( $I_{OUT}$ ) does not exist. (refer to the Oscillation Description ② below)
4. In order to stabilize the IC's operations, please ensure that  $V_{IN}$  pin's input frequency's rise and fall times are more than several  $\mu\text{s}/\text{V}$ .
5. Please use N-ch open drains configuration, when a resistor  $R_{IN}$  is connected between the  $V_{IN}$  pin and power source. In such cases, please ensure that  $R_{IN}$  is less than  $\text{k}\Omega$  and that  $C$  is more than  $0.1\mu\text{F}$ .

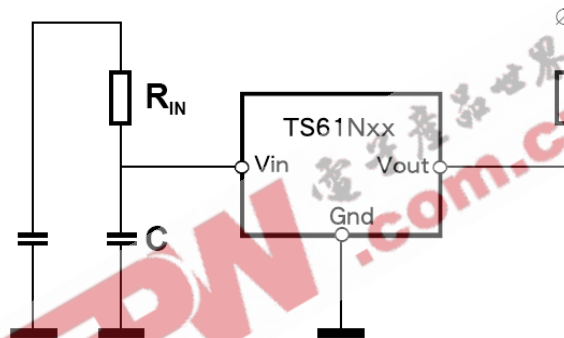


Diagram: Circuit using an input resistor

### Oscillation Description

#### OUTPUT CURRENT OSCILLATION WITH THE CMOS OUTPUT CONFIGURATION

When the voltage applied at IN rises, release operations commence and the detector's output voltage increases. Load current ( $I_{OUT}$ ) will flow at  $R_L$ . Because a voltage drop ( $R_{IN} \times I_{OUT}$ ) is produced at the  $R_{IN}$  resistor, located between the input (IN) and the  $V_{IN}$  pin, the load current will flow via the IC's  $V_{IN}$  pin. The voltage drop will also lead to a fall in the voltage level at the  $V_{IN}$  pin. When the  $V_{IN}$  pin voltage level falls below the detect voltage level, detect operations will commence. Following detect operations, load current flow will cease and since voltage drop at  $R_{IN}$  will disappear, the voltage level at the  $V_{IN}$  pin will rise and release operations will begin over again. Oscillation may occur with this "release-detect-release" repetition. Further, this condition will also appear via means of a similar mechanism during detect operations.

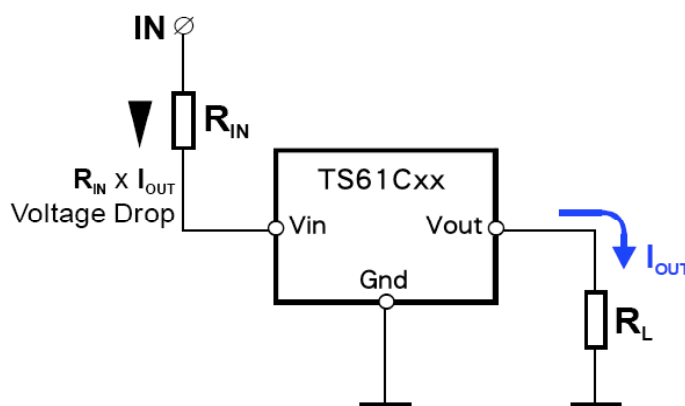
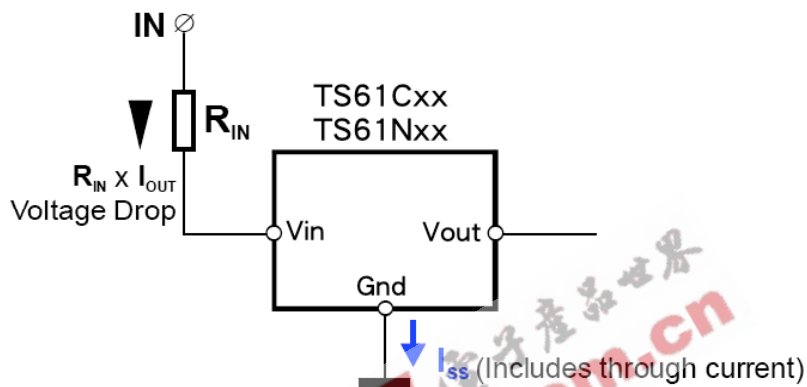


Diagram 1: Oscillation in relation to output current

### Oscillation Description (Continue)

#### OUTPUT CURRENT OSCILLATION WITH THE CMOS OUTPUT CONFIGURATION

Since the TS61 series are CMOS ICs, through current will flow when the IC's internal circuit switching operates (during release and detect operations). Consequently, oscillation is liable to occur as a result of drops in voltage at the through current's resistor ( $R_{IN}$ ) during release voltage operations (refer to diagram 2). Since hysteresis exists during detect operation, oscillation is unlikely to occur.

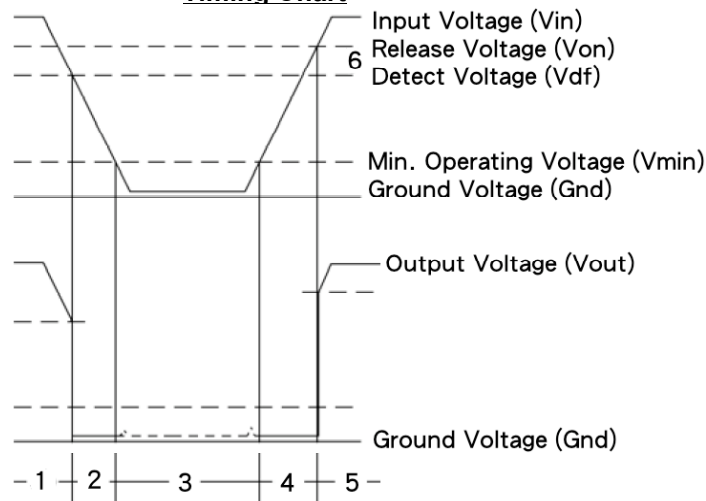


**Diagram 2: Oscillation in relation to through current**

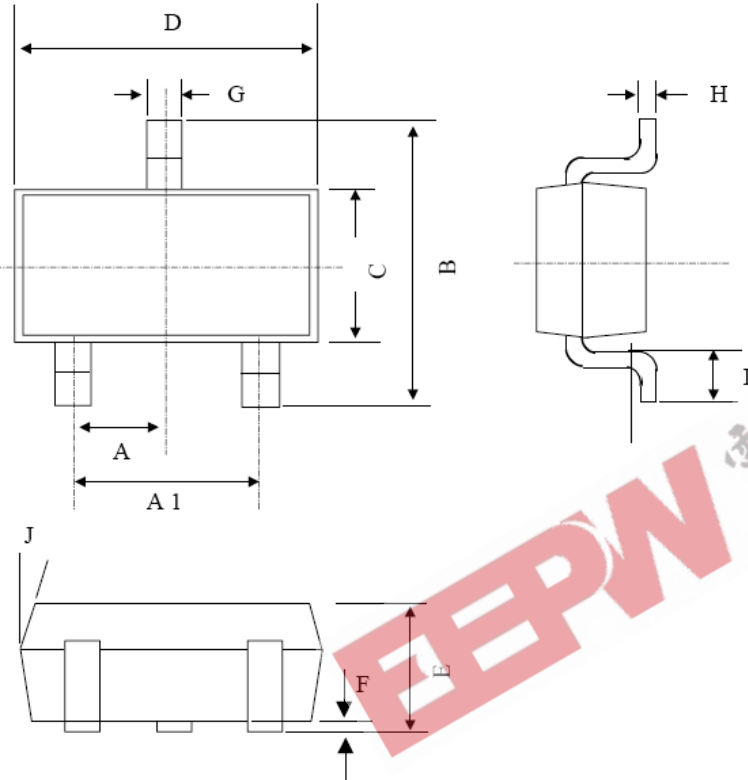
#### Function Description

1. When input voltage ( $V_{IN}$ ) rises above detect voltage ( $V_{DF}$ ), output voltage ( $V_{OUT}$ ) will be equal to  $V_{IN}$ . (A condition of high impedance exists with N-ch open drain output configurations).
2. When input voltage ( $V_{IN}$ ) falls below detect voltage ( $V_{DF}$ ), output voltage will be equal to the ground voltage ( $V_{SS}$ ).
3. When input voltage ( $V_{IN}$ ) falls to a level below that of the minimum operating voltage ( $V_{MIN}$ ), output will become unstable. In this condition,  $V_{IN}$  will equal the pulled-up output (should output be pull-up).
4. When input voltage ( $V_{IN}$ ) rises above the ground voltage ( $V_{SS}$ ) level, output will be unstable at levels below the minimum operating voltage ( $V_{MIN}$ ). Between the  $V_{MIN}$  and detect release voltage  $V_{DR}$  level, the ground voltage ( $V_{SS}$ ) level will be maintained.
5. When input voltage ( $V_{IN}$ ) rises above detect release voltage ( $V_{DR}$ ), output voltage ( $V_{OUT}$ ) will be equal to  $V_{IN}$ . (A condition of high impedance exists with N-ch open drain output configurations.)
6. The difference between  $V_{DR}$  and  $V_{DF}$  represents the hysteresis range.

#### Timing Chart



**SOT-23 Mechanical Drawing**



DIM	SOT-23 DIMENSION			
	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX.
A	0.95 BSC		0.037 BSC	
A1	1.9 BSC		0.074 BSC	
B	2.60	3.00	0.102	0.118
C	1.40	1.70	0.055	0.067
D	2.80	3.10	0.110	0.122
E	1.00	1.30	0.039	0.051
F	0.00	0.10	0.000	0.004
G	0.35	0.50	0.014	0.020
H	0.10	0.20	0.004	0.008
I	0.30	0.60	0.012	0.024
J	5°	10°	5°	10°

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